

## Linear Materials

### Macroscopic Maxwell Equations

$$\vec{\nabla} \cdot \vec{B} = 0 \quad \vec{\nabla} \times \vec{E} + \frac{1}{c} \frac{\partial \vec{B}}{\partial t} = 0$$

$$\vec{\nabla} \cdot \vec{D} = 4\pi\rho \quad \vec{\nabla} \times \vec{H} = \frac{4\pi}{c} \vec{j} + \frac{1}{c} \frac{\partial \vec{D}}{\partial t}$$

where  $\rho$  and  $\vec{j}$  are macroscopic charge & current densities  
and

$$\begin{aligned} \vec{D} &= \vec{E} + 4\pi \vec{P} & \vec{P} &\text{ is polarization density} \\ \vec{H} &= \vec{B} - 4\pi \vec{M} & \vec{M} &\text{ is magnetization density} \end{aligned}$$

To close these equations, we will in general need  
to know how  $\vec{P}$  and  $\vec{M}$  are related to the  $\vec{E}$  and  $\vec{B}$   
in the material.

In some materials, there can be a finite  $\vec{P}$  or  $\vec{M}$   
even if  $\vec{E}$  and  $\vec{B}$  are zero:

Ferromagnet:  $\vec{M}$  can be non zero even if  $\vec{B}=0$

Ferroelectric:  $\vec{P}$  can be non zero even if  $\vec{E}=0$

But more common are linear materials in  
which, for small  $\vec{E}$  and  $\vec{B}$ , one has  $\vec{P} \propto \vec{E}$   
and  $\vec{M} \propto \vec{B}$ .

### linear dielectric

$$\vec{P} = \chi_e \vec{E}$$

$\chi_e$  is "electric susceptibility"

$\chi_e > 0$  for statics

$$\vec{D} = \vec{E} + 4\pi \vec{P} = (1 + 4\pi \chi_e) \vec{E}$$

$$\vec{D} = \epsilon \vec{E} \quad \text{with } \epsilon = 1 + 4\pi \chi_e$$

$\epsilon$  is the dielectric constant

### linear magnetic materials

$$\vec{M} = \chi_m \vec{H}$$

$\chi_m$  is "magnetic susceptibility"

$\chi_m > 0 \Rightarrow$  paramagnetic

$\chi_m < 0 \Rightarrow$  diamagnetic

$$\vec{H} = \vec{B} - 4\pi \vec{M} = \vec{B} - 4\pi \chi_m \vec{H}$$

$$\vec{B} = (1 + 4\pi \chi_m) \vec{H}$$

$$\vec{B} = \mu \vec{H} \quad \text{with } \mu = 1 + 4\pi \chi_m$$

$\mu$  is magnetic permeability

For statics,  $\chi_e > 0$  and  $\chi_m$  (or alternatively  $\epsilon$  and  $\mu$ ) are constants depending on the material.

When we consider dynamics we will see that  $\epsilon$  becomes a function of frequency.



## Claussius - Mossotti equation

Electric susceptibility & atomic polarizability

If a field  $\vec{E}_{\text{loc}}$  is applied to an atom, it gets polarized

$$\vec{p} = \alpha \vec{E}_{\text{loc}}$$

↑  
atomic dipole moment      ↑ "local field" - field the atom sees  
                                atomic polarizability

$\alpha$  is what one calculates from a microscopic theory

If  $\vec{E}_{\text{loc}} = \vec{E}$  the average field in the material

then electric susceptibility given by

$$\vec{P} = m \vec{p} = m \alpha \vec{E}_{\text{loc}} = m \alpha \vec{E} = \chi_e \vec{E}$$

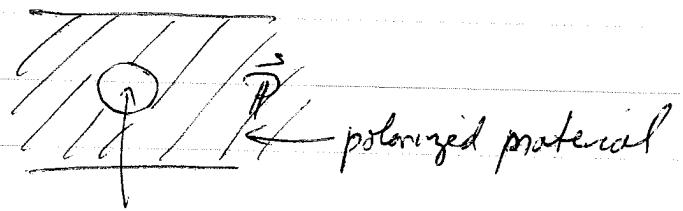
$$\Rightarrow \chi_e = m \alpha \quad \text{where } m = \text{density of atoms}$$

But a more careful consideration shows  $\vec{E}_{\text{loc}} \neq \vec{E}$

The average field  $\vec{E}$  includes the electric field created by the polarized atom itself.  $\vec{E}_{\text{loc}}$ , the local field the atom sees, should exclude its own self field.

$$\vec{E} = \vec{E}_{\text{loc}} + \vec{E}_{\text{atom}}$$

↑      ↑      ↓  
average field    average field excluding atom    average field of the atom



cut out sphere whose volume is  $V_n$   
the volume per atom

$\vec{E}_{loc}$  is field excluding the field of the polarized sphere of volume  $V_n$ .

$\vec{E}_{atom}$  is field of the polarized sphere

$$\vec{E}_{atom} = -\frac{4\pi \vec{P}}{3} = -\frac{4\pi}{3} m \vec{p}$$

$$\vec{E}_{loc} = \vec{E} - \vec{E}_{atom} = \vec{E} + \frac{4\pi}{3} \vec{P} = \vec{E} + \frac{4\pi}{3} m \vec{p}$$

$$\vec{p} = \alpha \vec{E}_{loc} = \alpha (\vec{E} + \frac{4\pi}{3} m \vec{p}) = \alpha \vec{E} + \frac{4\pi m \alpha}{3} \vec{p}$$

$$\vec{p} = \frac{\alpha \vec{E}_{loc}}{1 - \frac{4\pi m \alpha}{3}}$$

$$\vec{P} = m \vec{p} = \frac{\alpha m}{1 - \frac{4\pi m \alpha}{3}} \vec{E} = \chi_e \vec{E}$$

$$\chi_e = \frac{m \alpha}{1 - \frac{4\pi}{3} m \alpha}$$

or solve for  $\alpha$  in terms of  $\epsilon$

$$\chi_e = \frac{m\alpha}{1 - \frac{4\pi}{3}m\alpha} \Rightarrow \chi_e - \frac{4\pi m\alpha \chi_e}{3} = \alpha m$$

$$\Rightarrow \alpha = \frac{\chi_e}{m(1 + \frac{4\pi}{3}\chi_e)}$$

$$\epsilon = 1 + 4\pi\chi_e \Rightarrow \alpha = \frac{\epsilon - 1}{4\pi m} \frac{1}{(1 + \frac{\epsilon - 1}{3})}$$

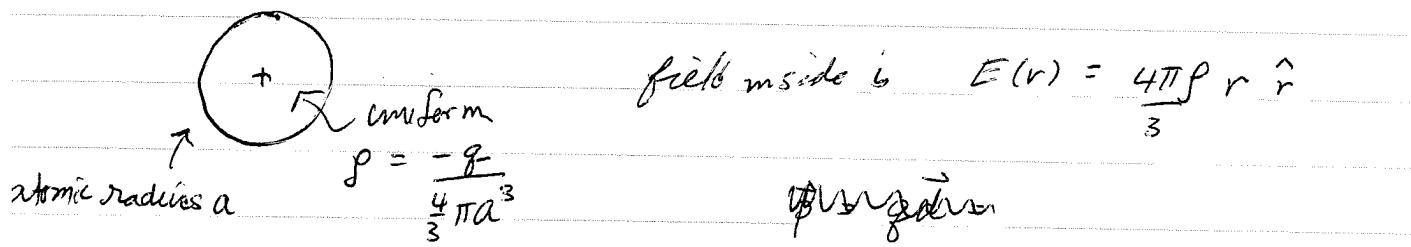
relates atomic  
polarizability to  
measured dielectric constant

$$\boxed{\alpha = \frac{3}{4\pi m} \left( \frac{\epsilon - 1}{\epsilon + 2} \right)}$$

Claudius Mosotti

or Lorentz-Lorenz equation

single model for  $\alpha$



In external field  $E_0$ , net forces balance  $\Rightarrow qE_0 = q \frac{4\pi\rho d}{3}$

$$\chi_e = \frac{ma^3}{1 - \frac{4\pi}{3}ma^3}$$

$$f = \frac{q}{4\pi\rho} = \frac{3}{4\pi} \frac{q}{\rho} E_0 = \frac{3}{4\pi} \frac{(4\pi a^3)}{\rho} q E_0$$

$$= a^3 E_0 \Rightarrow \boxed{\alpha = a^3}$$

if  $f = m \frac{4\pi a^3}{3}$  fraction of vol that is occupied by atoms

$$\boxed{\chi_e = \frac{1}{4\pi} \frac{3f}{1-f}}$$

## Linear dielectrics

bound charge is proportional to free charge

$$\rho_b = -\vec{\nabla} \cdot \vec{P} = -\vec{\nabla} \cdot (\chi_e \vec{E}) = -\vec{\nabla} \cdot \left( \frac{\chi_e}{\epsilon} \vec{D} \right)$$

if  $\chi_e$  (and hence  $\epsilon$ ) is spatially constant, then

$$\rho_b = -\frac{\chi_e}{\epsilon} \vec{\nabla} \cdot \vec{D} = -\frac{\chi_e}{\epsilon} 4\pi\rho$$

$$\boxed{\rho_b = -\frac{4\pi\chi_e}{1+4\pi\chi_e} \rho}$$

when free charge  $\rho = 0$ ,  
then  $\rho_b = 0$

$$\rho_{\text{total}} = \rho + \rho_b = \rho \left[ 1 - \frac{4\pi\chi_e}{1+4\pi\chi_e} \right] = \frac{\rho}{1+4\pi\chi_e} = \boxed{\frac{\rho}{\epsilon} = \rho_{\text{total}}}$$

bound charge "screens" the free charge so the total charge is reduced compared to the free charge.

## For linear dielectrics

### Statics

$$\vec{\nabla} \cdot \vec{D} = 4\pi\rho$$

$$\vec{\nabla} \times \vec{E} = 0$$

$$\vec{D} = \epsilon \vec{E} \Rightarrow \vec{\nabla} \cdot (\epsilon \vec{E}) = 4\pi\rho$$

If  $\epsilon$  is constant in space then  $\epsilon \vec{\nabla} \cdot \vec{E} = 4\pi\rho$

$$\begin{aligned} \vec{\nabla} \cdot \vec{E} &= 4\pi\rho/\epsilon = 4\pi\rho_{\text{tot}} \\ \vec{\nabla} \times \vec{E} &= 0 \end{aligned} \quad \left. \begin{array}{l} \text{look just like ordinary} \\ \text{electrostatics but} \\ \text{with } \rho \rightarrow \rho/\epsilon \end{array} \right.$$

Alternatively, could write  $\vec{E} = \vec{D}/\epsilon$

$$\Rightarrow \vec{\nabla} \times (\vec{D}/\epsilon) = 0$$

$$\Rightarrow \vec{\nabla} \times \vec{D} = 0 \quad \text{when } \epsilon \text{ constant in space}$$

$$\begin{aligned} \vec{\nabla} \cdot \vec{D} &= 4\pi\rho \\ \vec{\nabla} \times \vec{D} &= 0 \end{aligned} \quad \left. \begin{array}{l} \text{looks just like ordinary} \\ \text{electrostatics, but with } \vec{E} \rightarrow \vec{D} \end{array} \right.$$

Complication arises at interface between dielectrics (or between dielectric and vacuum). At interface,  $\epsilon$  is not constant  $\Rightarrow \vec{\nabla} \times \vec{D} \neq 0$ .

What we can do is to solve for  $\vec{E}$  or  $\vec{D}$  inside each dielectric separately, and then use the boundary conditions

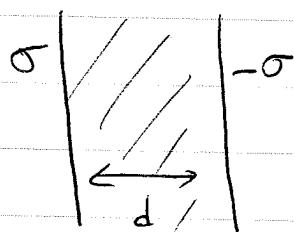
$$\hat{n} \cdot (\vec{D}_{\text{above}} - \vec{D}_{\text{below}}) = 4\pi\sigma$$

$$\hat{n} \cdot (\vec{E}_{\text{above}} - \vec{E}_{\text{below}}) = 0$$

to match solutions across the interfaces.

A similar story holds for linear magnetic materials

Simple example: parallel plate capacitor filled with a dielectric



$\sigma$  free charge

What is  $E$  between plates?

We know  $\vec{E} = \vec{D} = 0$  outside plates

Between plates  $\nabla \cdot \vec{D} = 0$  as  $\rho = 0$

$$\vec{D} = D(x) \hat{x} \Rightarrow \frac{\partial D}{\partial x} = 0 \Rightarrow D \text{ is constant}$$

Boundary conditions:

left side plate

$$\begin{cases} \hat{m} = \hat{x} \\ D = 0 \end{cases}$$

$$\hat{x} \cdot (\vec{D}_{\text{above}} - \vec{D}_{\text{below}}) = D = 4\pi\sigma$$

right side plate

$$\begin{cases} \hat{m} = \hat{x} \\ D = 0 \end{cases}$$

$$\hat{x} \cdot (\vec{D}_{\text{above}} - \vec{D}_{\text{below}}) = -D = 4\pi(-\sigma)$$

$$D = 4\pi\sigma \text{ as before}$$

$$\Rightarrow \vec{D} = 4\pi\sigma \hat{x}$$

$$\boxed{\vec{E} = \frac{\vec{D}}{\epsilon} = \frac{4\pi\sigma}{\epsilon} \hat{x}}$$

electric field reduced  
by factor  $1/\epsilon$  as compared  
to capacitor with vacuum  
between plates

see Jackson section 4.4 for more interesting examples  
- dielectric sphere in uniform applied  $E$

see Jackson section (5.11) for an interesting magnetic h.c. problem